

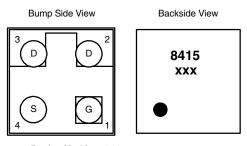
FREE

Vishay Siliconix

P-Channel 12 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)		
	0.037 at V _{GS} = - 4.5 V	- 7.3			
- 12	0.046 at V _{GS} = - 2.5 V	- 6.6	19		
	0.060 at V _{GS} = - 1.8 V	- 5.8			

MICRO FOOT



Device Marking: 8415 xxx = Date/Lot Traceability Code

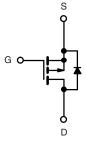
Ordering Information: Si8415DB-T1-E1 (Lead (Pb)-free and Halogen-free)

FEATURES

- TrenchFET[®] Power MOSFET
- MICRO FOOT[®] Chipscale Packaging Reduces Footprint Area Profile (0.62 mm) and RoHS COMPLIANT **On-Resistance Per Footprint Area** HALOGEN
- Ultra-Low On-Resistance
- Material categorization:
- For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

Load Switch, Charger Switch, and PA Switch for Portable Devices



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	$(T_A = 25 \ ^{\circ}C, unle$	ess otherwise	noted)		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 12		V
Gate-Source Voltage		V _{GS}	± 8		
	T _A = 25 °C	I _D	- 7.3	- 5.3	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 5.9	- 4.3	
Pulsed Drain Current		I _{DM}	- 25		A
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 2.5	- 1.3	
	T _A = 25 °C	PD	2.77	1.47	W
Maximum Power Dissipation ^a	T _A = 70 °C		1.77	0.94	
Operating Junction and Storage Temperature Ran	T _J , T _{stg}	- 55 to 150		00	
Package Reflow Conditions ^b IR/Convection			2	260	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 5 s	R _{thJA}	35	45	
Maximum Junction-to-Ambient ^a	Steady State		72	85	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	16	20	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. Refer to IPC/JEDEC (J-STD-020), no manual or hand soldering.

c. In this document, any reference to case represents the body of the MICRO FOOT device and foot is the bump.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	te Threshold Voltage $V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = -250$		- 0.4		- 1	V
Gate-Body Leakage	I _{GSS}				± 100	nA
Zara Cata Valtaga Drain Current	I _{DSS}	V _{DS} = - 12 V, V _{GS} = 0 V			- 1	
Zero Gate Voltage Drain Current		V_{DS} = - 12 V, V_{GS} = 0 V, T_{J} = 70 °C			- 5	μA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \leq$ - 5 V, V_{GS} = - 4.5 V	- 5			А
		$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$		0.031	0.037	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -1 \text{ A}$		0.038	0.046	Ω
		V _{GS} = - 1.8 V, I _D = - 1 A		0.050	0.060	l.
Forward Transconductance ^a 9 _{fs}		V _{DS} = - 10 V, I _D = - 1 A		11		S
Diode Forward Voltage ^a	V _{SD}	$I_{S} = -1 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.8	- 1.1	V
Dynamic ^b						
Total Gate Charge	Qg			19	30	
Gate-Source Charge	Q _{gs}	V_{DS} = - 6 V, V_{GS} = - 4.5 V, I_D = - 1 A		1.9		nC
Gate-Drain Charge	Q _{gd}			4.8		
Gate Resistance	R _g	f = 1 MHz		19		Ω
Turn-On Delay Time	t _{d(on)}			15	25	
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		32	50	
Turn-Off Delay Time	t _{d(off)}	I_D \cong - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		180	270	ns
Fall Time	t _f			115	175	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1 A, dl/dt = 100 A/μs		80	120	

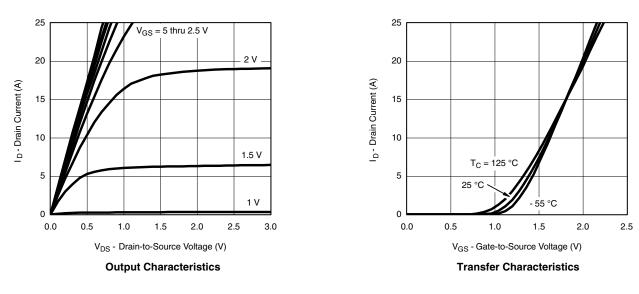
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



For technical questions, contact: pmostechsupport@vishay.com

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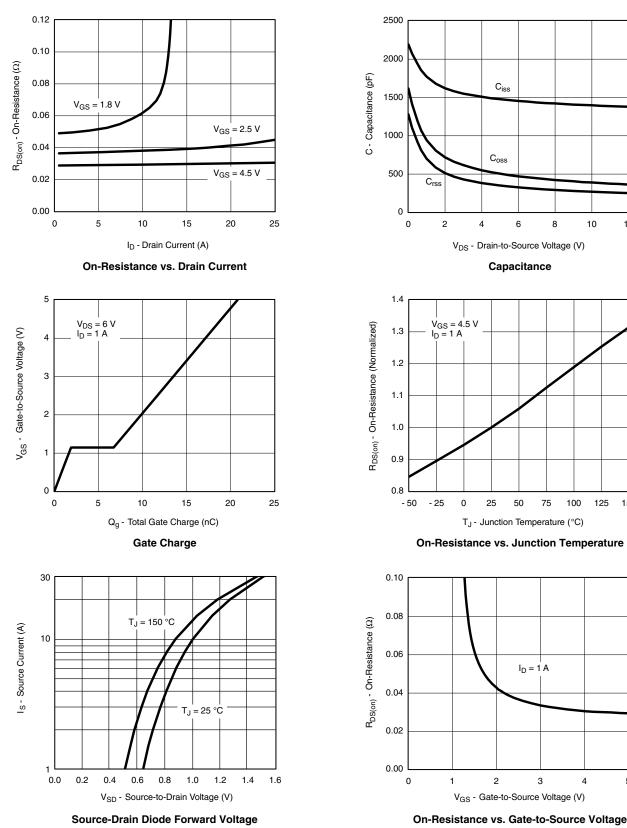


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150

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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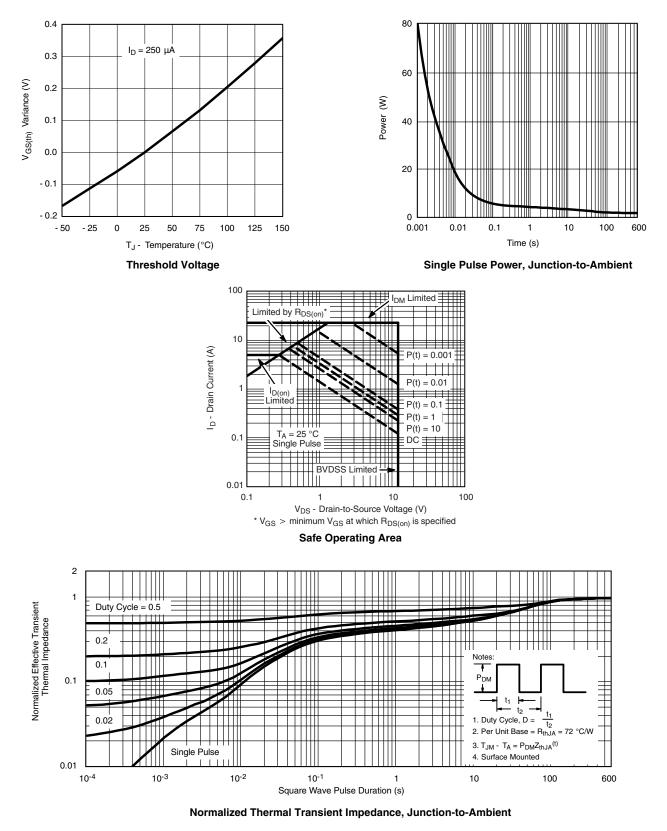
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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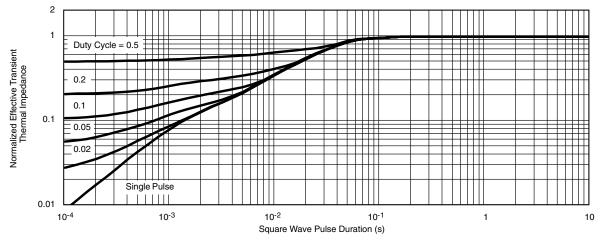
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

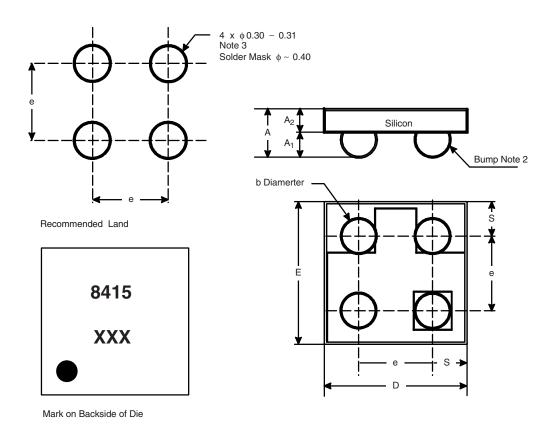
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PACKAGE OUTLINE

MICRO FOOT: 4-BUMP (0.8 mm PITCH)



Notes (unless otherwise specified):

- 1. Laser mark on the silicon die back, coated with a thin metal.
- 2. Bumps are 95.5/3.8/0.7 Sn/Ag/Cu.
- 3. Non-solder mask defined copper landing pad.
- 4. The flat side of wafers is oriented at the bottom.

Dim.	Millim	eters ^a	Inches		
	Min.	Max.	Min.	Max.	
Α	0.600	0.650	0.0236	0.0256	
A ₁	0.260	0.290	0.0102	0.0114	
A ₂	0.340	0.360	0.0134	0.0142	
b	0.370	0.410	0.0146	0.0161	
D	1.520	1.600	0.0598	0.0630	
E	1.520	1.600	0.0598	0.0630	
е	0.800		0.03	315	
S	0.360	0.400	0.0142	0.0157	

Notes:

a. Use millimeters as the primary measurement.

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